L Number	Hits	Search Text	DB	Time stamp
13	26	(negative adj resistance) near9 npn	USPAT;	2004/04/21 16:29
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
14	3	(negative adj resistance) near9 (transistor diode) near9 amp	USPAT;	2004/04/21 16:32
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
16	0	((negative adj resistance) near9 (transistor diode) near9	USPAT;	2004/04/21 16:33
		current) near9 ((gas adj insulating adj apparatus) adj	US-PGPUB;	
		ampere)	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
17	0	((negative adj resistance) near9 (transistor diode) near9	USPAT;	2004/04/21 16:33
	i	current) near9 (one adj ampere)	US-PGPUB;	
			EPO; JPO;	
	İ İ		DERWENT;	
15	224	(manakiya ndi yasiahayas) masyo (hususiahay diada) yasao	IBM_TDB	2004/04/24 45 45
15	334	(negative adj resistance) near9 (transistor diode) near9	USPAT;	2004/04/21 16:46
		current	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
18	0	20030071676.URPN.	IBM_TDB USPAT	2004/04/21 16:36
19	28724	power adj (transistors diodes)	USPAT;	2004/04/21 16:36
10	20724	porter day (dansistors aloues)	US-PGPUB;	2007/07/21 10.4/
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
20	o	(power adj (transistors diodes)) near9 (negative adj	USPAT;	2004/04/21 16:47
		resistance)	US-PGPUB;	200 1/0 1/21 10.47
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	